# LT0R45M/LT0R45P

#### **Features**

- (1) Maximum optical power output: 4.5mW\*1
- (2) Wavelength: 650nm band
- (3) With built-in high speed OPIC\*(MIN.20MHz) External noise solution is unnecessary
- (4) Gain switching (writing/reading)
- (5) Compact package (4.8mm thickness)
- (6) High temperature operation: MAX. 70°C

\*OPIC: (Optical IC) is a trademark of the SHARP Corporation. An OPIC consists of a lightdetecting element and signal-processing circuit integrated onto a single chip.

#### Model No.

- LT0R45M....Dual power supply
- LT0R45P ....Single power supply

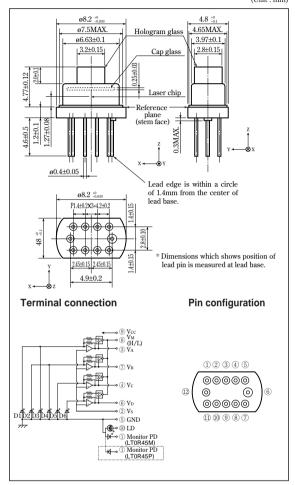
## **Applications**

(1) ×2 speed DVD players

# **Compact Size Hologram Laser for** DVD(650nm-Single Mode)

#### **Outline Dimensions**

(Unit:mm)



#### **Absolute Maximum Ratings**

■ Absolute Maximum Ratings (Tc=25°						
Param	eter	Symbol	Rating	Unit		
*1 Optical power outpo	ıt	Рн	4.5	mW		
Reverse voltage	Laser	$V_R$	2	V		
Keverse voltage	Monitor photodiode		30	V		
OPIC supply voltag	Vcc	6	V			
*2 Operating temperat	*2 Operating temperature			°C		
*2 Storage temperatur	Tstg	-40 to +85	°C			
*3 Soldering temperat	ure	Tsold	260(5s or less)	°C		

Output power from hologram laser

#### SHARP

Case temperature

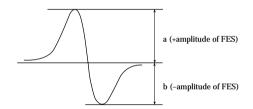
At the position of 1.6mm or more from the lead base

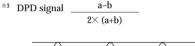
### Flectro-ontical Characteristics

Electro-optical Characteristics						(Vcc=5V,	Vs=1/2Vc	c, Tc=25°C)	
	Parameter Symbol		Condit	ions	MIN.	TYP.	MAX.	Unit	
#1	Focal offset		DEF	V <sub>RF</sub> =0.34V		-0.7	-	+0.7	μm
#2	Focal error symm	etry	Bres	Vrf=0.	34V	-25	-	+25	%
#3	Radial error balar	ice	Bres	Рн=3.0	mW	-25	-	+25	%
*4	RF output	High gain	Vrfh			0.55	0.75	-	$V_{p-p}$
	amplitude I	Low gain	Vrfl	Рн=3.0	mvv	0.25	0.34	-	V <sub>p-p</sub>
#5	FEC	VFES		0.437	0.10	0.10	0.05	17	
₩.J	FES output ampli	tuae	IFES	$ m V_{RF}=0.34V$		0.12	0.18	0.25	$V_{p-p}$
*** DEG ( )		Vres	V. 0.04V.		.1.1		.1.1	**	
₩0	**6 RES (p.p) output amplitude		Ires	Vrf=0.34V		t.b.d	t.b.d	t.b.d	V <sub>p-p</sub>
	Threshold curren	t	Ith	_		-	45	75	mA
	Operating curren	t	Iop	Рн=2.85mW		-	54	80	mA
	Operating voltage	<b>;</b>	Vop	P <sub>H</sub> =2.85mW		-	2.2	3.0	V
	Wavelength		$\lambda_{p}$	Рн=2.85mW		640	654	660	nm
	Polarization mode			Рн=2.85	5mW		TE		
Monitor current			т.	Рн=2.85mW,	LT0R45M	0.03	0.08	0.30	
			Im	$V_{R}=15V$	LT0R45P	0.015	0.04	0.15	mA
Differential official 1.9r		W	0.10	0.00	0.55	XX// A			

I(2.85mW)-I(0.95mW)

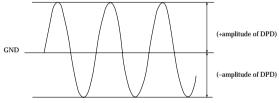
Differential efficiency





a-b

0.13

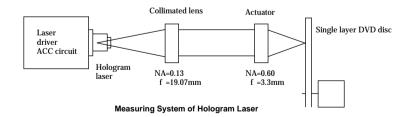


0.33

0.55

mW/mA

- \*\*4 Amplitude of Va+VB+Vc+VD (focal servo ON, radial servo ON)
- \*5 VA-VB (Focal vibration)
- \*6 DPD signal amplitude (focal servo ON)



Distance between FES=0 and jitter minimum point At the condition of FES sensitivity =  $25\%/1\mu m$ 

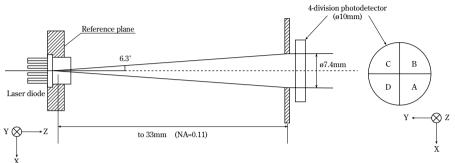
<sup>(</sup>a-b) / (a+b)

# ■ Electro-optical Characteristics of Laser Diode (Design Standard)

(Tc=25°C)

Para	meter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Radiation	*7 Symmetry	Parallel	SII	Po=3mW,	-25	-	+25	%
characteristics	Symmetry	Perpendicular	S⊥	into NA=0.11	-15	-	+15	%
Emission point accuracy			$\Delta x$	t	-80	-	+80	μm
		Position	$\Delta y$	ı	-80	-	+80	μm
			$\Delta z$	1	-80	-	+80	μm

<sup>\*7</sup> Measuring method of radiation symmetry



Parameter	Definition
sII	$\frac{(P_{\rm B} + P_{\rm C}) - (P_{\rm A} + P_{\rm D})}{P_{\rm A} + P_{\rm B} + P_{\rm C} + P_{\rm D}}$
s⊥	$\frac{(P_A + P_B) - (P_C + P_D)}{P_A + P_B + P_C + P_D}$

Px: Output of light detector X

# ■ Electrical Characteristics of Monitor Photodiode (Design Standard)

(Tc=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*8 Sensitivity	S	$V_R=15V$	-	0.028	-	mA/mW
Dark current	$I_{\rm d}$	$V_R=15V$	-	-	150	nA
Terminal capacitance	Ct	$V_R=15V$	-	9	-	pF

<sup>\*\*8</sup> For hologram output power

# ■ Electro-optical Characteristics of OPIC for Signal Detection (Design Standard)

(Tc=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	*9 Segment
Supply voltage	Vcc	_	4.5	-	5.5	V	-
Supply voltage	Vs	Vs=1/2Vcc	2.25	-	2.75	V	-
Supply current	Icc	Vcc=5V	3	6	9	mA	-
*10 Output off-set voltage	Vod	Vcc=5V	-15	0	+15	mV	Va,Vb,Vc,Vd
Off-set voltage difference	$\Delta V_{\mathrm{OD}}$	No light	-15	0	+15	mV	Va-VB,Vc-VD
Response frequency	fcr	*11 Vcc=5V, -3dB	20	-	-	MHz	Va,VB,Vc,VD

<sup>\*9</sup> Applicable divisions correspond to pattern segment No.

D6	
D4	
D3	
D2	
D1	
D5	

Segmen	nt No.	Output
D1+D2.		VA
D3+D4.		V <sub>B</sub>
D5		Vc
D6		V <sub>D</sub>

<sup>\*10</sup> Difference from Vcc/2

<sup>\*\*11</sup> Output amplitude=0dB (input signal 100kHz) 6µW/segment when input light is 650nm. Load resistance Ri=10kΩ, load capacitance Ci=10pF

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  - Gas leakage sensor breakers
  - Alarm equipment
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